COMPLIANT





High-Speed, Low ron, SPDT Analog Switch

(2:1 Multiplexer)

DESCRIPTION

The DG2307 is a single-pole-double-throw switch/2:1 mux designed for 2 to 5.5 V applications. Using Vishay Siliconix proprietary sub-micro CMOS process, the DG2307 achieves low on-resistance, low power consumption. It is 1.6 V TTL logic compatible across the operation voltage range. With its low r_{ON} and low parasitic capacitance character, it is ideal for clock signal and high speed data stream switching. It has low insertion lost and negligible propagation delay.

The DG2307 can handle both analog and digital signals and permits signals to be transmitted in either direction. When Bn pin is at off status, the path will have a high impedance with respect to the output. Break before make is guaranteed.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100 % matte tin device terminations, the lead (Pb)-free "-E3" suffix is being used as a designator.

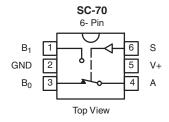
FEATURES

- Operates From Single 2 ~ 5.5 V
- SC70-6 Package
- 5 Ω Switch Connection Between Ports
- Minimal Propagation Delay
- TTL Compatible Input Level
- RoHS Compliant

APPLICATIONS

- Cellular Phones
- PDAs
- GPS
- MP3
- Data Acquisition

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: G1

TRUTH TABLE	
Logic Input (S)	Function
0	B ₀ Connected to A
1	B ₁ Connected to A

ORDERING INFORMATION					
Temp Range	Package	Part Number			
- 40 to 85 °C	SC70-6	DG2307DL-T1-E3			

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ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
Reference V+ to GND		- 0.3 to + 6	V		
S, A, B ^a		- 0.3 to (V+ + 0.3 V)	V		
Continuous Current (Any terminal)		± 50	A		
Peak Current (Pulsed at 1 ms, 10 %	duty cycle)	± 200	mA		
Storage Temperature	(D Suffix)	- 65 to 150	°C		
Power Dissipation (Packages) ^b	6-Pin SC70 ^c	250	mW		

Notes:

- a. Signals on A, or B or S exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 3.1 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS								
		Test Conditions Otherwise Unless Specified			Limits - 40 to 85 °C		°C	
Parameter	Symbol	V+ = 3.0 V,	$V_S = 0.25 \text{ V to } 0.7 \text{ V+}^e$	Temp ^a	Min ^b	Typ ^c	Max ^b	Unit
DC Characteristics								
High Level Input Voltage	V_{SH}	V+	= 2.3 to 5.5 V	Full	0.7 V+			V
Low Level Input Voltage	V_{SL}	V+	= 2.3 to 5.5 V	Full			0.3 V+	ľ
		V+ = 4.5 V	$V_{BN} = 0 \text{ V}, I_{A} = -30 \text{ mA}$	Full		4	6	Ω
On Resistance	R _{ON} -		V _{BN} = 2.3 V, I _A = - 30 mA	Full		9	12	
		V+ = 3.0 V	V _{BN} = 0 V, I _A = - 24 mA	Full		6	9	
			V _{BN} = 1.5 V, I _A = - 24 mA	Full		13.5	20	
On Resistance Matching	A.D.	V+ = 4.5 V, V _{BN} = 0 V, I _A = - 30 mA V+ = 3.0 V, V _{BN} = 0 V, I _A = - 24 mA		Room		0.32		
Between Channels	ΔR_{ON}			Room		0.31		1
Input Leakage Current	Is	V+ = 5.5 V, V _A = 5.5 V		Room Full	- 0.1 - 1.0		0.1 - 1.0	
Off Stage Switch Leakage	I _{BN(off)}	$V+ = 5.5 \text{ V}, V_A/V_B = 0 \text{ V}/5.5 \text{ V}$		Room Full	- 0.1 - 1.0		0.1	μA
On State Switch Leakage	I _{BN(on)}	V+ = 5.5 V, V _A /V _B = 0 V/5.5 V		Room Full	- 0.1 - 1.0		0.1 - 1.0	
Power Supply								
Power Supply Range	V+			Full	2		5.5	
Quiescent Supply Current	l+	V+ = 5.5 V, V _A = V _B = V+ or GND		Room Full			1 10	μΑ





SPECIFICATIONS								
		Test Conditions Otherwise Unless Specified $V+=3.0 \text{ V}, V_S=0.25 \text{ V} \text{ to } 0.7 \text{ V}+^e$			Limits - 40 to 85 °C			
Parameter	Symbol			Temp ^a	Min ^b	Typ ^c	Max ^b	Unit
AC Electrical Characteristics								
Prop Delay Time ^f		V _A = 0 V	V+ = 2.3 to 2.7 V	Full		1.2		-
	t _{PHL} /t _{PLH}		V+ = 3.0 to 3.6 V	Full		0.8		
			V+ = 4.5 to 5.5 V	Full		0.3		
		$V_{LOAD} = 2 \times V + \text{ for } t_{PZL}$ $V_{LOAD} = 0 \text{ V for } t_{PZH}$	V+ = 2.3 to 2.7 V	Room Full		5.9 6.2		
Output Enable Time ^f	t _{PZL} /t _{PZH}		V+ = 3.0 to 3.6 V	Room Full		4.1 4.5		
			V+ = 4.5 to 5.5 V	Room Full		2.6 2.9		
		$V_{LOAD} = 2 \times V + \text{ for } t_{PLZ}$ $V_{LOAD} = 0 \text{ V for } t_{PHZ}$	V+ = 2.3 to 2.7 V	Room Full		5.9 6.2		ns
Output Disable Time ^f	t _{PLZ} /t _{PHZ}		V+ = 3.0 to 3.6 V	Room Full		4.1 4.5		
			V+ = 4.5 to 5.5 V	Room Full		2.6 2.9		
		V+ = 2.3 to 2.7 V		Full	0.5			1
Break-Before-Make Time ^d	t _{BBM}	V+ = 3.0 to 3.65 V		Full	0.5			1
		V+ = 4.5 to 5.5 V V+ = 2.3 to 2.7 V V+ = 3.0 to 3.65 V V+ = 4.5 to 5.5 V	Full	0.5				
Charra Iniantiand	Q	$C_L = 0.1 \text{ nF, } V_{GEN} = 0 \text{ V}$	V+ = 5 V	Room		7		рС
Charge Injection ^d	Q	$R_{GEN} = 0 \Omega$	V+ = 3.3 V	Room		3		рС
Analog Switch Characteristic	s							
Off Isolation ^d	OIRR	V+ - 5 V R 50) O f = 10 MHz	Room		- 57.6		dB
Crosstalk ^d	X _{TALK}	$V+ = 5 V$, $R_L = 50 Ω$, $f = 10 MHz$		Room		- 58.7		ub
- 3 db Bandwidth ^d	BW	$R_L = 50 \Omega$		Room		250		MHz
Capacitance								
Control Pin Capacitance ^d	C _{IN}	V+ = 0 V		Room		4.9		
B Port Off Capacitance ^d	C _{IO-B}			Room		6.5		pF
A Port Capacitance When Switch Enable ^d	C _{IO-A(on)}	V+ = 5 V		Room		18.5		- P'

Notes:

- a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.

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LOGIC DIAGRAM (POSITIVE LOGIC)

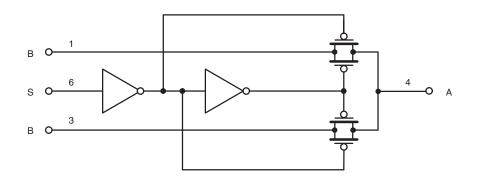
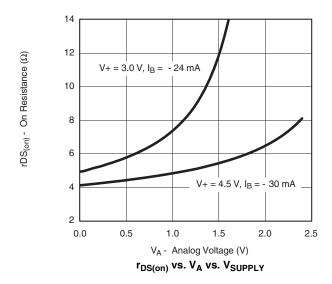
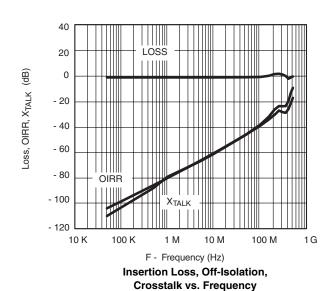


Figure 1.

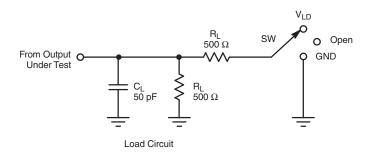
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







AC LOADING AND WAVEFORMS



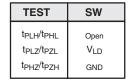


Figure 2. AC Test Circuit

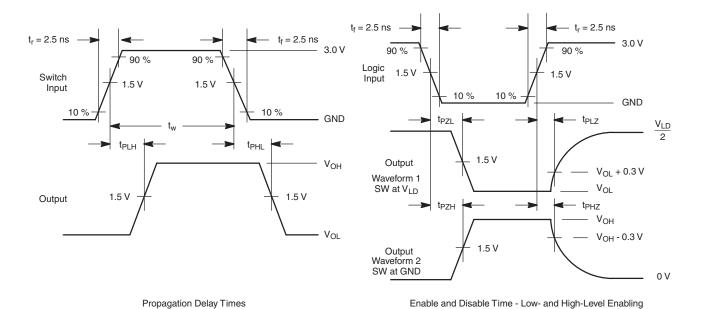


Figure 3. AC Waveforms

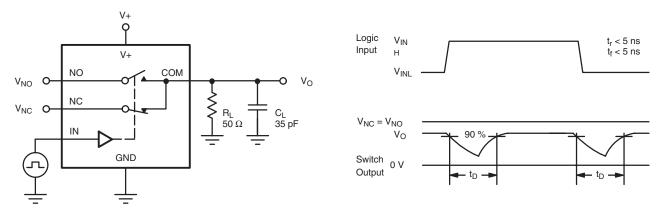
Notes

- a. $\ensuremath{C_L}$ includes probe and jig capacitance.
- b. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- c. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- d. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$.
- e. The outputs are measured one at a time with one transition per measurement.
- f. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- g. $t_{\mbox{\scriptsize PZL}}$ and $t_{\mbox{\scriptsize PZH}}$ are the same as $t_{\mbox{\scriptsize dis}}$
- h. t_{PLH} and t_{PHL} are the same as t_{dis} .
- i. $V_{LD} = 2 V +$.

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TEST CIRCUITS



C_L (includes fixture and stray capacitance)

Figure 4. Break-Before-Make Interval

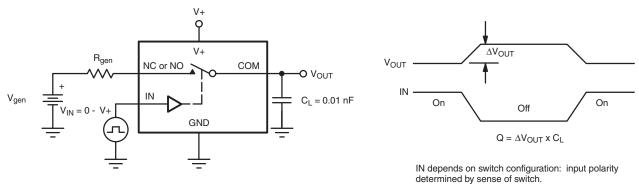


Figure 5. Charge Injection

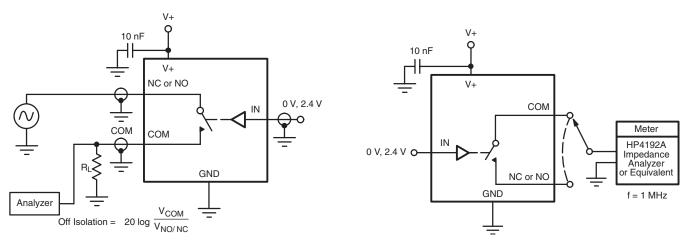


Figure 6. Off-Isolation

Figure 7. Channel Off/On Capacitance

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